



### EPITAXIAL PLANAR NPN TRANSISTOR

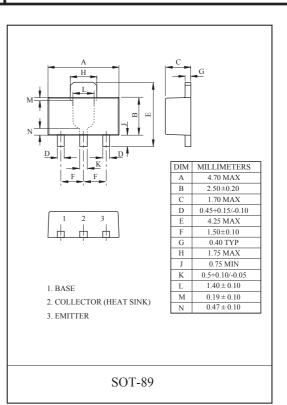
#### HIGH CURRENT APPLICATION.

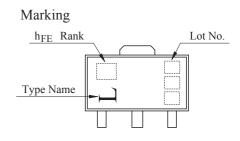
### FEATURES

- · High DC Current Gain
  - :  $h_{FE}$ =800 ~ 3200. ( $V_{CE}$ =5.0V, I<sub>C</sub>=300mA).
- · Wide Area of Safe Operation.
- · Low Collector Saturation Voltage
  - :  $V_{CE(sat)}=0.17V (I_C=500mA, I_B=5.0mA)$ .

## MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Collector-Base Voltage	V <sub>CBO</sub>	60	V	
Collector-Emitter Voltage	V <sub>CEO</sub>	50	V	
Emitter-Base Voltage	V <sub>EBO</sub>	8	V	
Collector Current	I <sub>C</sub>	1.0	А	
Collector Power Dissipation	P <sub>C</sub>	500	mW	
	P <sub>C</sub> *	1	W	
Junction Temperature	Tj	150	°C	
Storage Temperature Range	T <sub>stg</sub>	-55~150	°C	





# $P_{C}^{*}$ : KTD1003 Mounted on Ceramic Substrate (250mm<sup>2</sup>x0.8t)

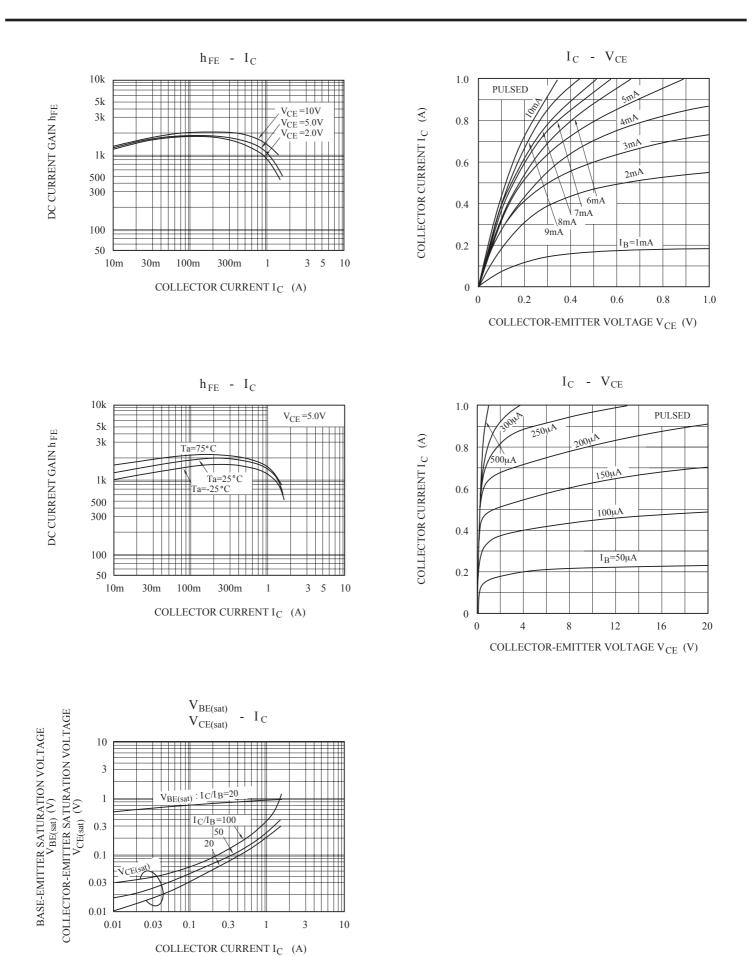
## ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I <sub>CBO</sub>	$V_{CB}=60V, I_{E}=0$	-	-	100	nA
Emitter Cut-off Current	I <sub>EBO</sub>	$V_{EB}=8V, I_C=0$	-	-	100	nA
DC Current Gain	h <sub>FE</sub> (1) Note	V <sub>CE</sub> =5.0V, I <sub>C</sub> =300mA	800	1500	3200	
	$h_{FE}(2)$	V <sub>CE</sub> =5.0V, I <sub>C</sub> =1.0A	400	-	-	
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =5.0mA	-	0.17	0.30	V
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =5.0mA	-	0.80	1.2	V
Collector Output Capacitance	C <sub>ob</sub>	$V_{CB}=10V, I_{E}=0, f=1.0MHz$	-	18	30	pF
Transition Frequency	$\mathbf{f}_{\mathrm{T}}$	$V_{CE}$ =10V, I <sub>C</sub> =500mA, f=100MHz	150	250	-	MHz
Base-Emitter Voltage	V <sub>BE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =100mA	-	630	700	mV

Note :  $h_{FE}$  Classification A:800 ~ 1600, B:1200 ~ 2400, C:2000 ~ 3200



# **KTD1003**





#### PRECAUTION ON USING KEC PRODUCTS

1. The products described in this data are intended to be used in general-purpose electronic equipment (Office equipment, telecommunication equipment, measuring equipment, home appliances)

2. When you intend to use these products with equipment or device which require an extremely high of reliability and special applications (such as automobile, air travel aerospace, transportation equipment, life support, system and safety devices) in which special quality and reliability and the failure or malfunction of products may directly jeopardize or harm the human body or damage to property and any application other than the standard application intended, please be sure to consult with our sales representative in advance.

3. On designing your application, please use product within the ranges guaranteed by KEC for maximum rating, operating supply voltage range, heat radiation characteristics and other characteristics. User shall be responsible for failure or damage when used beyond the guaranteed ranges.

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5. What are described in the data may be changed without any prior notice to reflect new technical development. Please confirm that you have received the latest product standards or specification before final design, purchase or use.

6. Although KEC is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors. Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. KEC shall have no responsibility for any damages arising out of the use of our Products beyond the rating specified by KEC.



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